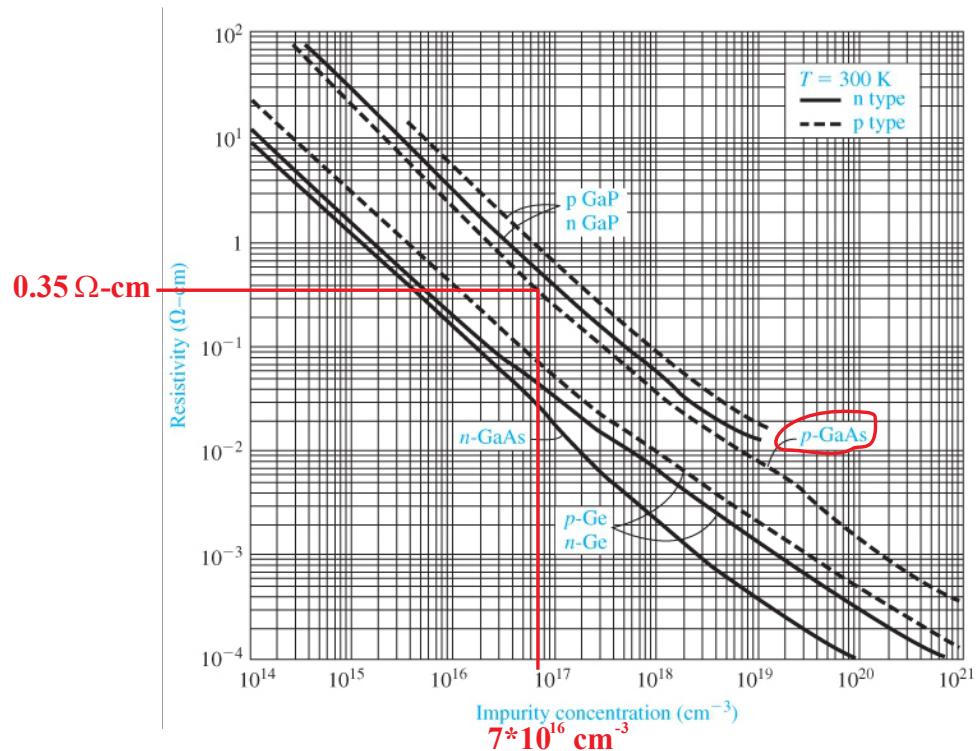
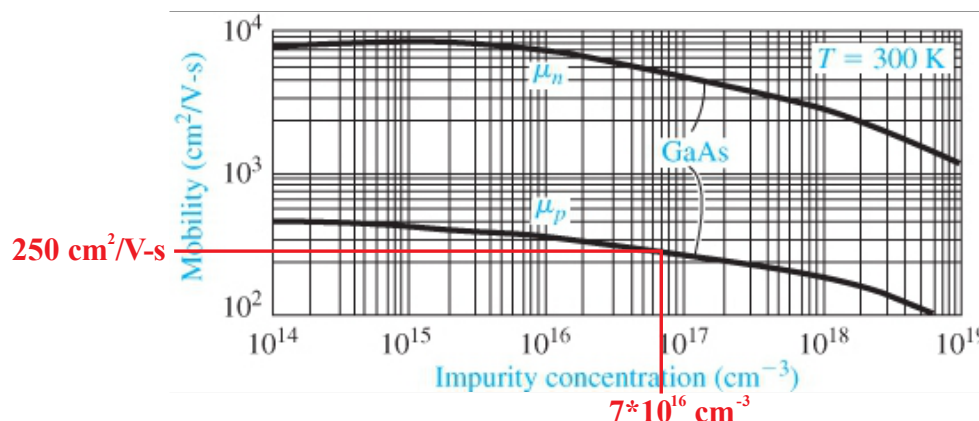


- 5.4** (a) The resistivity of a p-type GaAs material at $T = 300$ K is required to be $\rho = 0.35 (\Omega\text{-cm})$. Determine the acceptor impurity concentration that is required. What is the hole mobility corresponding to this impurity concentration? (b) An n-type GaAs material is required to have a conductivity of $\sigma = 120 (\Omega\text{-cm})^{-1}$. What donor impurity concentration is required and what is the corresponding electron mobility?
- a)** The intrinsic charge concentration, $n_i = 1.8 \times 10^6 \text{ \#/cm}^3$ (Table B.4), is negligible compared to N_a . So, $p \approx N_a$. We'll assume $N_d = 0$. Per (5.20), $\rho = 1/[e(\mu_n N_d + \mu_p N_a)] \cong 1/(e \mu_p N_a)$. Using Fig. 5.4b, the impurity concentration for p-type GaAs is **$N_a = 7 \times 10^{16} \text{ \#/cm}^3$** .



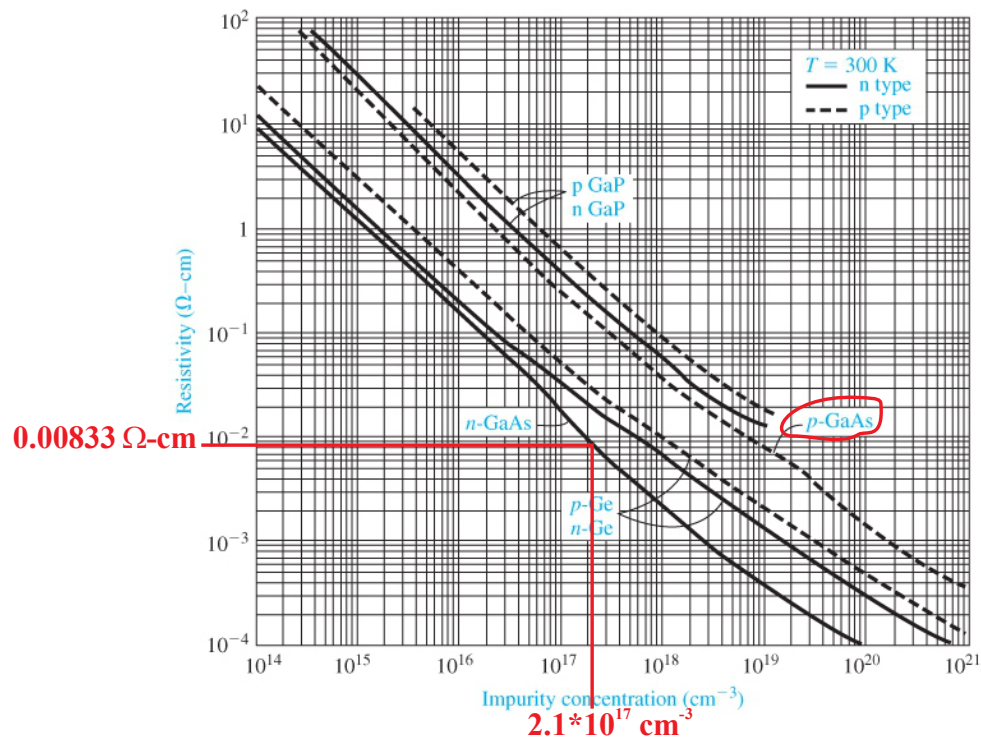
From Semiconductor Physics and Devices: Basic Principles (4th Edition), Donald A. Neamen, McGraw Hill, 2012, ISBN 978-0-07-352958-5.

Going to Figure 5.3 (bottom graph for GaAs), we read the electron mobility for this impurity concentration is **$\mu_p \approx 250 \text{ cm}^2/\text{V-s}$** .



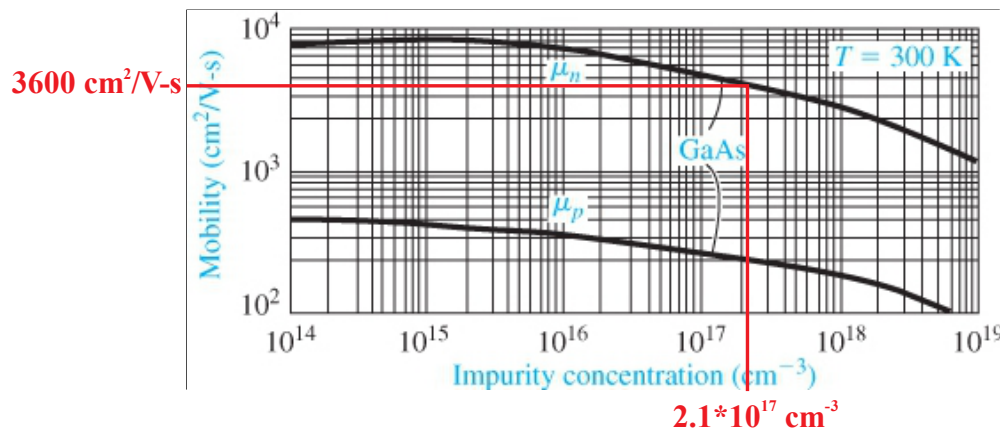
Check- $\rho \cong 1/(e \mu_p N_a) = 1/[1.6022 \times 10^{-19} (250) 7 \times 10^{16}] = 0.357 \Omega\text{-cm}$. [decent agreement]

b) The intrinsic charge concentration, $n_i = 1.8 \times 10^6 \text{ \#/cm}^3$, is negligible compared to N_d . So, $n \approx N_d$. Assume $N_a = 0$. Per (5.23), $\sigma = e(\mu_n N_d + \mu_p N_a) \cong e \mu_n N_d = 120 (\Omega\text{-cm})^{-1}$ and $\rho = 1/\sigma = 1/120 = 0.00833 \Omega\text{-cm}$. Using Fig. 5.4b, the impurity concentration for the n -type GaAs is $N_d = 2.1 \times 10^{17} \text{ \#/cm}^3$.



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Going to Figure 5.3 (bottom graph for GaAs), we can read what the electron mobility for this impurity concentration is $\mu_n \approx 3600 \text{ cm}^2/\text{V-s}$.



Check- $\sigma \cong e \mu_n N_d = 1.6022 \times 10^{-19} (3600) 2.1 \times 10^{17} = 121.1 (\Omega\text{-cm})^{-1}$. [decent agreement]